N ovel D esigns for Penning Ion traps

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W e present a num ber of alternative designs for Penning ion traps suitable for quantum inform ation processing (Q P) applications with atom ic ions. The rst trap design is a simple array of long straight wires which allows easy optical access. A prototype of this trap has been built to trap C a⁺ and a simple electronic detection scheme has been employed to demonstrate the operation of the trap. Another trap design consists of a conducting plate with a hole in it situated above a continuous conducting plane. The nal trap design is based on an array of pad electrodes. A line this trap design lacks the open geom etry of the traps described above, the pad design may prove useful in a hybrid scheme in which inform ation processing and qubit storage take place in di erent types of trap. The behaviour of the pad traps is simulated num erically and techniques for moving ions rapidly between traps are discussed. Future experiments with these various designs are discussed. A ll of the designs lend them selves to the construction of multiple trap arrays, as required for scalable ion trap Q P.

1 Introduction

A conventional Penning trap consists of three electrodes: a ring electrode and two endcaps. Ideally these electrodes are hyperboloids of revolution, producing a quadrupole electric potential, and traps with hyperbolic electrodes are common place. Trapping of positive ions is achieved by holding the endcaps at a positive potential with respect to the ring electrode. This provides one dimensional connement along the axis of the trap. The electrode structure is embedded in a strong axial magnetic eld which provides connement in the other two dimensions (the radial plane). This conguration has proven to be useful in mass-spectrom etry measurements and fundamental studies with single ions [1]. An important variant of the Penning trap employs a stack of cylindrical electrodes. Typically ve electrodes are used { a thin ring electrode, a pair of the penning trap employs a stack of cylindrical electrodes that act as the endcaps. The geometry of this arrangement means that it is well suited for use with superconducting solenoid magnets. This design has a slightly more been' geometry than the hyperbolic trap since it has good access along the axis of the trap. Nonetheless, neither of these designs are really ideal for applications such as spectroscopy and Q IP studies where optical access is of prim ary importance.

A scheme has been proposed that uses a linear array of cylindrical Penning traps for Q IP using trapped electrons [2]. This scheme uses m icrowave techniques rather than optical addressing so that optical access is not an issue. This approach has limited scalability since the array of traps is essentially one dimensional. To address this issue, further work on this scheme is now being focussed on a new planar trap design [3]. This design has an open geometry and is readily scalable to two dimensional arrays. A trap of this variety has recently been tested and trapped electrons were successfully detected [4]. The Q IP scheme envisaged by Stahlet al. [3] involves electrons in di erent m icro-traps being coupled via superconducting wires.

A nother proposal has been m ade for a very simple trap m ade using straight w ires [5]. This trap shares the optical accessibility of the Stahlet al. [3] design and lends itself, in a very straightforward way, to the production of arrays of traps. The basic trap consists of two perpendicular sets of three parallel straight w ires (see gure 1). This trap utilizes an electrostatic potential between the central and the outer w ires to con ne the ions axially, with a magnetic eld providing con nem ent in the other two dimensions. A nother advantage of this trap is that an analytical expression exists for the equation of motion of trapped ions. In this paper a rst prototype of the wire trap is presented with experimental evidence of its operation.

Current ion trap Q IP experiments focus on strings of ions in linear radiofrequency traps, however this approach is unlikely to be scalable beyond a few tens of ions. The issue of scalability in ion trap Q IP has been carefully addressed in a paper by K ielpinski et al. [6]. They describe a scheme based on trapped ions held in multiple miniature rf ion traps. In this scheme two ions are loaded into a single micro-trap where gate operations may be performed. Individual ions are then shuttled into dierent micro-traps for storage and can be retrieved at a later time to continue with the calculation. In the last few years a number of key elements of this approach have been demonstrated [7].

A dapting this approach to the Penning trap involves a number of challenges, however, Penning traps m ay have some important advantages. Am bient magnetic eld uctuations have been shown to be the m a jor limiting cause of decoherence in radiofrequency ion trap Q IP to date. O perating a radiofrequency trap with a small additional magnetic eld at which the 'qubit' transition frequency is rst-order B - eld independent has been shown to lead to coherence times greater than 10 seconds [8]. On the other hand, coherence times of up to 10 m inutes have been dem onstrated using sim ilar techniques in a Penning trap [9]. A nother advantage of the Penning trap is that it employs only static electric and magnetic elds and so heating rates should be very low in these traps. Shuttling ions between di erent Penning traps along the axis of the magnetic eld is straightforward [10], but moving ions in a two dimensional array of traps, as required for scalability, will inevitably involve moving ions in a plane perpendicular to the magnetic eld. This is complicated by the presence of the v B term in the Lorentz force. In this paper we address this issue and describe a possible architecture for a Penning trap quantum information processor. We consider two alternative approaches. The rst is to allow the ion to drift in the desired direction ('adiabatic' approach). Clearly, speed is a concern for QIP so we have also considered a diabatic' approach in which an ion is hopped' to a desired location in a single cyclotron loop by the application of a pulsed nearly linear electric eld. In order to be able to switch between a linear eld (for hopping) and a quadrupole potential (for trapping), a di erent arrangem ent of electrodes is required. The resulting traps are made up from arrays of pad electrodes whose voltages can be switched rapidly in order to perform the di erent required operations.

2 The wire trap

A simple trap based on two sets of three wires or rods is shown schem atically in Fig. 1. This arrangement of wires produces minima in the electric potential. At these points, the forces between the charged particle and the various electrodes (wires) cancelout and thus charged particles can be three-dimensionally conned with the addition of a magnetic eld in the axial direction. A more complete description of this trap can be found in [5]. Brie y, the electrostatic potential produced by the six wire ion trap, in Cartesian coordinates, is

$$(x;y;z) = \frac{4 V}{2 \ln (d^2 = 2a^2)} \ln \frac{R^2}{(x+d)^2 + (z+z_0)^2} \ln \frac{R^2}{x^2 + (z+z_0)^2} + \ln \frac{R^2}{(x-d)^2 + (z+z_0)^2}$$

$$\frac{4 \text{ V}}{2 \ln (d^2 = 2a^2)} \ln \frac{R^2}{(y+d)^2 + (z-z_0)^2} - \ln \frac{R^2}{y^2 + (z-z_0)^2} + \ln \frac{R^2}{(y-d)^2 + (z-z_0)^2} :$$
(1)

where d is the distance between two wires, $2z_0$ is the distance between two sets of wires, a is the diam eter of the wires (a d), R is an arbitrary distance at which the potential is set to zero, R d, and 4 V is the potential di erence between central and external wires [5]. From the latter equation it is possible to nd at least three m inim a along the axial direction (z): above, below and between the wires. The experimental setup presented here is focused on the study of trapped ions in the minimum at the centre of the trap

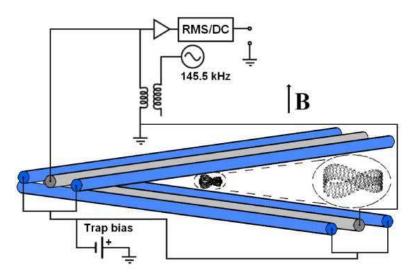


Figure 1. Six wire trap and electronic detection scheme. The simulated trapped ion trajectory shown in the gure (with an expanded view in the oval inset) corresponds to Ca⁺ at 10 m eV in a trap with similar dimensions to those of the prototype. The potential dimensione between central and external wires is 4 V = 1:3 V (at this voltage, the axial frequency of ions corresponds to the resonant frequency of the detection circuit). The magnetic eld of 1 T is oriented perpendicular to both set of wires. The simulation was performed using SIM IO N.

(between the two wire planes), however future work will investigate the optical detection of ions at all three trapping points.

2.1 Experim ental setup

We have built a prototype of this trap and have included a simple electronic detection scheme, also shown in Fig.1. The dimensions of the trap were chosen to tinto standard DN 40 CF vacuum components. The wire' electrodes consist of two sets of three stainless-steel cylindrical rods of 1 mm diameter and approximately 35 mm long. W ithin a set, the centres of the wires are separated by 3 mm and the centres of the wires are 4 mm apart in the axial direction. The rods are supported by ceram ic mounts and xed into an oxygen-free copper base which is mounted on the electrical feedthrough. The copper base has a 2 mm hole below the trap center to perm it the access of electrons from a lam ent placed behind it, but also to shield the trapping volume from the electric eld produced by the lament and its connectors. Calcium atom s are produced by an atom ic beam oven and are ionized by electron bom bardm ent to produce Ca^+ . The calcium oven is made of a 1 mm diameter tantalum tube spot-welded onto a 0.25 mm tantalum wire. Calcium is placed inside the tantalum tube and then both ends of the tube are closed. A hole ($0.2 \,\mathrm{mm}$ diameter) in the side of the tube allows atom s to e use into the trapping region when the oven is heated by an electrical current sent through the tantalum wire. The electron lament is made of coiled thoriated tungsten wire with a diam eter of 0.25 mm. The trap has been operated at 2.5 10^8 mbar and with a magnetic eld of 1 T. The calcium oven is driven at 1.53 Amps and the lament at 4.4 Amps. The lament 30 V with respect to the grounded rods to accelerate electrons into the trapping region. is biased by

For the electronic detection of ions, the trap is connected to a simple resonant circuit where the applied D C trap bias is scanned so that the axial resonance of the ions in the trap passes through the resonance of the circuit (see F ig. 1). The resonant frequency of the circuit is 145.5 kH z and the amplitude of the drive is 10 m V_{p} p. If ions are present in the trap the quality factor of the resonance is modiled as the ions absorb energy from the circuit. The response of the circuit is monitored and rectiled with an rm s-D C converter. The presence of ions in the trap should therefore be accompanied by a change in the resulting D C signal. Experimental results are shown in Fig. 2. The upper curve (circles) is the result when the electron lament is switched o so that the trapping volume contains no charged particles. The lower curve (triangles) is the result when the electron lament is on but the oven, producing calcium atom s, is switched o. The reduction of the signal is due to the presence of electrons in the trapping volume. A lthough this a ects the circuit there is no particular resonance since the electrons are not trapped. The central curves (stars)

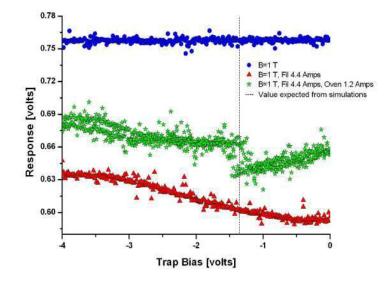


Figure 2. Experim ental results of the electronic detection scheme for Ca^{+} .

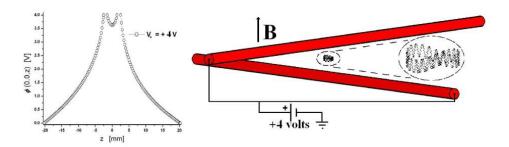


Figure 3. Simulation of the motion of a 40 C a⁺ ion in a two-wire trap performed using SIM ION. Ion kinetic energy 10 meV, a = 0.5 mm, $z_0 = 2 \text{ mm}$ and B = 1 T. The trajectory is shown enlarged in the oval inset. The potential generated by the trap is shown on the left.

result when both electrons and calcium atom s are present. We note a ubiquitous hysteresis when scanning the voltage from below resonance compared to scanning from above resonance. The resonant feature for calcium ions is predicted from simulations to occur at -1.35 V and is observed within the range of 1.5 to

1:1 V. This initial result demonstrates that the trap operates successfully and an experiment to perform laser cooling and optical detection of the Ca^+ ions in this trap is currently being prepared.

2.2 The two-wire trap

A wire trap can also be form ed with just two wires. Using the same notation as in Eq. 1, the electrostatic potential of two crossed wires separated by $2z_0$ is

$$= \frac{V_{+}}{\ln (R^{2} = az_{0})} \quad \ln \frac{R^{2}}{y^{2} + (z - z_{0})^{2}} + \ln \frac{R^{2}}{x^{2} + (z + z_{0})^{2}}$$
(2)

where V_+ is the electric potential of the wires with respect to a ground at R. The axial potential in Eq. 2 presents a minimum at z = 0 where charged particles can be conned (see Fig. 3). Following the same procedure as in [5], an approximate quadratic function around the potential minimum (x = 0, y = 0,

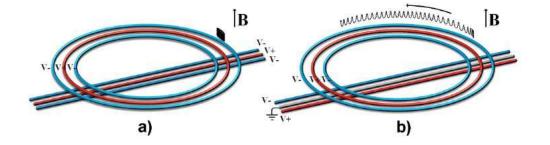


Figure 4. Simulations of a trap design to transport ions. In (a) external wires are connected to 5V, and central wires to + 5V. In (b) the upper set of wires is connected as in (a), the three lower wires are connected to 3V, 0V, + 5V respectively. Simulations perform ed using SIM ION for Ca⁺ with initial kinetic energy 100 m eV.

z = 0) can be found, giving the result

$$= \frac{2V_{+}}{\ln (R^{2} = az_{0})} 2 \ln \frac{R}{z_{0}} \frac{1}{z_{0}^{2}} x^{2} + y^{2} 2z^{2} : \qquad (3)$$

If an axialm agnetic eld (B) is added, the equations of m otion of an ion with m ass m and charge q around the m inim um are then

$$x = !_{c}\underline{y} + \frac{!_{z}^{2}}{2}x$$
; $y = !_{c}\underline{x} + \frac{!_{z}^{2}}{2}y$; $z = !_{z}^{2}z$

which are the well-known equations of motion of an ion inside a Penning trap, where $!_z^2 = 8qV_+ = m z_0^2 \ln (R^2 = az_0)$ and $!_c = qB = m$.

The two-wire con guration has three disadvantages compared to the six-wire trap: it does not produce trapping points above and below the trap, the harm onicity of the potential cannot be modiled, and the trap depth is smaller than for the six-wire trap design. One advantage how ever is that this trap would be easier to scale and construct allowing even greater optical access to the trapped ions. In Fig. 3 a simulation of a trapped Ca⁺ ion is presented when the electrodes of a two-wire trap are connected to +4 V.

2.3 'A diabatic' Ion Transfer in W ire Traps

C onditions for the transport of ions can be generated using these wire traps. In ref [5] it is shown that a circular 'ion guide' can be made using three concentric wire rings with trapping zones along circular lines directly above and below the structure. The goal would be to trap ions at one position and then transport them to another position where they could be manipulated. One way to achieve this is to use a circular set of three wires as an ion guide in combination with a straight set of wires, as illustrated in Fig. 4. In this example, the trapping region above the six wire electrodes is used. In Fig. 4a the simulation of a trapped C a^+ ion is observed in the crossing zone to the right of the gure, where both sets of wires are connected to a potential di erence of -10 V. In Fig. 4b, the upper set of wires is still connected to the original potential creating an ion guide along its path, but the lower straight set of wires has been connected in such a way that they produce a potential gradient which pushes the ions away from the old trapping region and around the ring. W hen the ions reach the left hand crossing region the voltages on lower set of wires can be adjusted to the same levels as in Fig. 4a producing trapping conditions again. W e term this kind of transport 'adiabatic' since the ion undergoes many cyclotron loops as it moves in the electric potential.

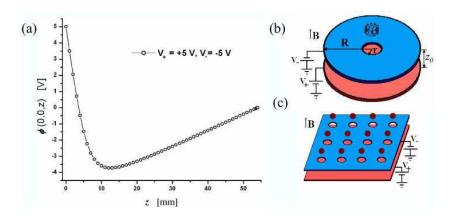


Figure 5. (a) The axial potential generated by the two-plate trap shown in (b) for $z_0 = 5 \text{ mm}$ and R r = 10 mm and with the electrodes connected to 5 volts as shown. The simulated trapped ion trajectory shown in (b) corresponds to a molecular ion with a mass of 100 am u and with an initial kinetic energy of 100 meV in an applied magnetic eld of B = 1 T as shown. The simulation was perform ed using SIM ION. (c) An array of traps based on this design.

3 The two-plate trap.

We also present here a proposal for a single-endcap trap and computer simulations of it. This proposal is essentially a modi cation of a planar trap [3], but with a simpler design together with straightforward scalability.

The trap presented in $[\beta]$ consists of a central disk connected to a positive voltage surrounded by a planar ring connected to a negative voltage; the entire system is surrounded by a grounded electrode and is embedded in a planar substrate. This design has a number of advantages including the ability to modify the vertical position of the trapping zone individually for each trap in the array, a feature which is essential for the Q IP scheme using trapped electrons proposed in ref [3]. On the other hand making individual connections to an array of traps clearly enorm ously increases the complexity of the structure. In the geom etry shown in F ig. 5b the two electrodes of the trap described above are deposited on separate planes. An array of such traps can then be generated with only two electrical connections to the entire structure (see gure 5c). C learly, this has the disadvantage not allowing individual control of the traps but such an array may induces in any scheme e where an array of trapped ions simply acts as a quantum register (for example the h oving head' scheme proposed by C irac and Zoller [11].

E sentially this trap is made of two planar electrodes positioned in di erent planes (z = 0 and $z = z_0$). The upper electrode is a planar ring with outer radius R and inner radius r in the plane $z = z_0$. The lower electrode is a disk of radius R in the plane z = 0. This trap can be also understood as a modi ed Penning trap with one of its endcaps rem oved, em ploying a planar ring electrode and a planar endcap. This type of con guration is able to produce an axial trapping potential above the electrodes when they are oppositely charged; con nem ent in the radial plane is produced by the addition of a magnetic eld perpendicular to the electrode planes. To dem onstrate this, an axial electrostatic potential is shown in F ig. 5a. A simulated trajectory for a trapped ion in this trap are shown in F ig. 5b. A s mentioned above, this trap geometry, like the two-w ire trap described earlier, exhibits great scalability with relative ease of construction and has good optical access due to the open structure.

4 Pad traps

We now consider a di erent design of trap array that lends itself to the rapid movement of ions from one trap to another. To see how this may be achieved rst consider the motion of an ion in crossed hom ogeneous electric and magnetic elds. If we assume the magnetic eld is in the positive z direction and a hom ogeneous electric eld is applied in the positive y direction, the trajectory of an ion that starts

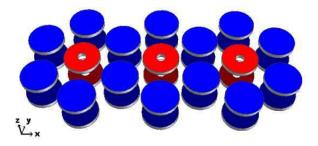


Figure 6. Schem atic layout of three pad traps. The 'endcap' electrodes have holes in them to allow for the loading and extraction of ions in the z-direction.

at rest at the origin is given by the parametric equations

$$x = \frac{V_{D}}{I} \sin ! t + V_{D} t$$
(4)

$$y = \frac{v_{\rm D}}{!} (1 \quad \cos ! t) \tag{5}$$

where $V_D = E = B$ is the drift velocity' and ! = qB = m is the cyclotron frequency. The motion is therefore a series of loops in the xy plane such that the ion drifts in the x direction, periodically coming to rest in the y direction. Consider a pair of traps whose axes are along the z-direction but whose centres are displaced in the x direction. If the trapping potential could be switched o and replaced by a linear electric eld as described above it would be possible to hop' the ion from the centre of one trap to the centre of the other trap in a single cycloid bop'. A first the hop' the trapping potential would be re-applied.

An ion completes a single cycloid loop in a time t = 2 = ! i.e. in a single cyclotron period. For ${}^{40}Ca^+$ and B = 1T we have t = 2.6 s. The size of the cycloid loop is determ ined by the magnitude of the electric eld since the displacement along the x axis as a result of the cycloid loop is given by $x_1 = (E = B) t$. For ${}^{40}Ca^+$ and B = 1T we have $x_1 = 2.6 \quad 10^{-6}E$. Thus an electric eld of 1900Vm⁻¹ is required for a displacement of 5mm. If the typical trap dimension is of the same order as this displacement, a typical voltage applied to an electrode would be in the region of 20V for a trap with a characteristic dimension of 1cm.

The traps must be operable in two distinct modes: a horm all trapping mode, and a mode in which a nearly linear electric eld can be applied across the entire structure (hopping' mode). The key design criterion is therefore to be able to switch rapidly between these two modes. The trap array we envisage is made up of two non-conducting substrates onto which a regular pattern of pad electrodes has been deposited.W e envisage connections to these electrodes being m ade through the back of the substrate.W e consider a pattern built up from a unit cell' that is an equilateral triangular array of three pads. A single quadrupole trap can then be realised in the following way: one substrate would hold a hexagonal array of six pads form ing a Ying' with a central pad acting as an Endcap'. The other substrate would carry an identical array of pads. The two opposing layers can then be made to form a trap using 14 electrodes in total { two endcaps and two sets of six pads making a pair of rings. By applying a positive potential to the endcaps and equal negative potentials to the elements of the rings a quadrupole potential can be generated at the centre of the structure. O ther traps can then be made by repeating this pattern in the radial plane (see gure 6). We have modelled the trapping potential using SIM ION. For our simulations we have chosen pads with a diameter of 4mm and a gap between the centres of the pads of 5mm. The potential can be optim ised by adjusting the 'aspect ratio' of the trap (i.e. the ratio of the separation of the layers to the separation of the pad centres in the xy plane), such that the deviation of the potential from a pure quadrupole is m in in ised. Figure 7a shows the deviation of the potential from a pure quadrupole potential for the optimum value of = 0:9. The endcap' electrodes have 1mm central holes to allow for the loading and extraction of ions along the z-direction. For the optim um value of the holes only disrupt the quadrupole potential signi cantly for relatively large values of z.

Figure 7b shows the potential in the radial plane at the midpoint between the substrates (z = 0). For a perfect Penning trap the contours projected onto the x;y plane would be circular. The deviation from circular symmetry is small over the trapping region despite the ring being comprised of six separate

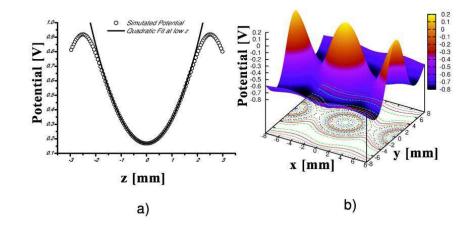


Figure 7. (a) The potential along the axis of the trap for = 0:9. The potential only deviates from quadratic behaviour close to the hole in the endcap. (b) P lot of the potential in the x;y plane at the m idpoint between the substrates. G ood circular sym m etry is evident for sm all displacements from the centre of each trap.

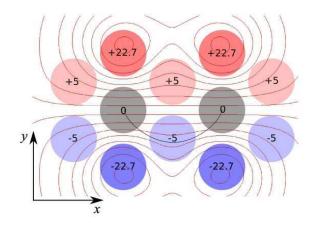


Figure 8. Applying the potentials shown to the individual pads causes transfer of an ion from the centre of the righthand trap to the centre of the lefthand trap (the magnetic eld is along the + z axis i.e. out of the page). The trajectory of an ion initially at rest at the centre of the righthand trap is shown for one cyclotron period.

electrodes.

In order to hop' an ion from one trapping site to another, a nearly linear electric eld is applied to the trap array. This is done by switching the potentials on the electrodes from the values used for trapping to the ones shown in gure 8. The gure also shows the contours of the resulting potential in the z = 0 plane. These potentials are chosen so that a single bycloid' loop takes a C a⁺ ion from one trapping zone to the other assuming a magnetic eld of 1T. Since the equipotential surfaces are not exactly planar the resulting trajectory does not have the exact shape of a bycloid loop', how ever, provided the ion's velocity has no component in the y-direction at the midpoint between the traps, symmetry dictates that the ion willend up in the centre of the second trap. This means that signi cant deviations from a linear eld can be tolerated. In fact, it is possible to choose the potentials applied to the pads in such a way as to generate a more nearly linear electric potential than the one shown in gure 8. How ever, since a genuinely linear potential is not strictly required we have chosen a set of potentials that o er the signi cant advantage of providing axial (z) con nem ent throughout the hop'. The trajectory of the ion in the z = 0 plane is show n in gure 8. For this trajectory the ion is assumed initially to be at rest at the middle of the rightm ost trap.

To dem onstrate the con nem ent in the axial direction gure 9 shows plots of the axial positions of ions z(t) as a function of time. The ions start at the centre of the rightmost trap and have a range of initial velocities (see gure caption). A xial con nem ent is assured because the chosen applied potentials generate a three-dimensional electric potential that has a minimum at z = 0 all the way along the ion's trajectory in the x;y plane. If we de net s as the displacement along this trajectory we can show this by plotting the

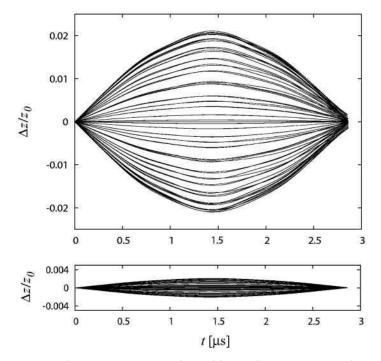


Figure 9. Simulations (perform ed using SIM ION) of the axial positions of ions z (t) as a function of time, for exactly one cyclotron period. The ions start at the centre of the righthand trap and have a range of initial velocities. For all cases the ions end up near to the centre of the lefthand trap in the xy plane. The upper panel assumes an initial kinetic energy 10 m eV. The initial direction of motion is varied over the full range of azim uth and declination in steps of 10 degrees. The low er panel shows a similar plot but with initial kinetic energy of 0.1 m eV. In the z-direction the ions are 'focused' into the second trap i.e. the naldeviation along the z-axis as a result of the hop is small.

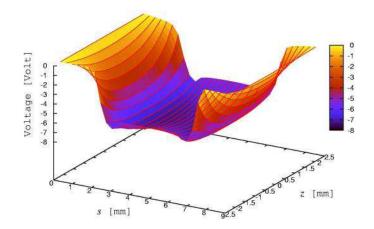


Figure 10. The potential in the z-direction evaluated at a range of equidistant points along the ions trajectory.

electric potential along the z axis as a function of s. This is shown in gure 10. The potential is dom inated by the steep slopes, rst negative and then positive, encountered along the trajectory s. This describes the ion rst accelerating predom inately in the y direction due to the near-linear electric eld, but eventually turning around and climbing back up the electric potential as the v B term becomes signi cant. On the other hand a close exam ination of the gure reveals that the potential in the z direction always has a m inim um at the position of the ion. The depth of this potential varies along the ion's trajectory so that the z-m otion is not harm onic during the hop', but the curvature of the potential ensures axial con nem ent. Since the ions at all times in them selves in a potential that has a minimum in the z direction they are 'boused' into the lefthand trap.

Finally we consider how such an array of pad' traps could be used for Q IP. We envisage a structure in which a stack of bonventional' cylindrical Penning traps could be positioned above one of the pad traps. Such a linear array of cylindrical traps along the magnetic eld direction could be used for gate operations between pairs of ions or multiple ions. Ions could then be ejected from the cylindrical stack into the pad trap directly below it. Ions in the pad trap array could then be shifted sideways allowing for a di erent ion to be presented to the linear stack of traps. We intend to build and test a prototype set of pad traps with the dimensions described above. It may be prudent to use closely spaced hexagonal pads rather than circular ones to minim ise the exposed are of non-conducting substrate which may be prone to charging up. Ultimately one could use microfabrication techniques to make much smaller pad-traps. The size is only limited by the amount of radial con nem ent that can be achieved, which depends on the strength of the magnetic eld. Furtherm ore, the geometry of these traps would allow the ions to be axialised [12], further in proving the localisation in the radial plane. U sing a 10T superconducting m agnet the hopping' time for Ca⁺ ions would be 260ns. Large arrays of pads could in principle be fabricated, in which case the pads could e ectively act as 'bixels' allowing almost arbitrary electric elds to be generated. Finally we note that a third option for moving ions in such an array of Penning traps is possible. If rather larger electric elds were applied an ion might be shifted in the direction of the applied electric eld so rapidly B component of the Lorentz force has a negligible bending e ect on the trajectories. Sm all that the v residual sideways shifts of the ion could be compensated by appropriate choice of the direction of the nearly linear electric eld applied. Whilst shifts could then in principle be achieved very rapidly, such an approach would require very ne control of the switched potentials, since an ion would need to be rst accelerated and nally decelerated as it approached its destination. One of the great advantages of the hopping' technique considered above is that the ion autom atically com es to rest in its new position, and so one can expect rather low heating e ects as a result of the shifting of the ion.

5 Conclusions

We have presented an experimental setup and experimental evidence for trapped ions inside a simple Penning trap made using a simple array of rods. We have also discussed a variety of other novel Penning traps all of which lend them selves to miniaturisation. We have discussed various strategies form oving ions around in arrays of miniature Penning traps and have set out some of their advantages for applications in Q IP. In particular we have described a hybrid quantum information processor based upon a stack of conventional cylindrical Penning traps, used for gate operations, and a two-dimensional array of 'bad' traps, in which stored ions act as a quantum register.

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References

- [1] P.K. Ghosh, Ion Traps, (Oxford University Press, 1995).
- [2] G. Ciaram icoli, I. Marzoli, and P. Tombesi Scalable Quantum Processor with Trapped Electrons', Phys. Rev. Lett. 91, 017901-1 (2003).
- [3] S. Stahl, F. G alve, J. A lonso, S. D jekic, W . Quint, T. Valenzuela, J. Verdu, M . Vogel, and G W erth A planar Penning trap'. Eur. Phys. J.D 32, 139146 (2005)
- [4] Private communication, M. Vogel and F. Galve, GSI and University of Mainz, Germany.
- [5] J.R. Castrejon-Pita and R.C. Thompson, Proposal for a planar Penning ion trap', Phys. Rev. A, 72 013405 (2005).
- [6] D.K ielpinski, C.M onroe and D.J.W ineland, A rchitecture for a large-scale ion-trap quantum computer'N ature 417 709 (2002).
- [7] M. D. Barnett, J. Chiaverini, T. Schaetz, J. Britton, W. M. Itano, J. D. Jost, E. Knill, C. Langer, D. Leibfried, R. Ozeri, and D. J. Wineland, Nature 429, 737 (2004); J. Chiaverini, J. Britton, D. Leibfried, E. Knill, M. D. Barnett, R. B. Blakestad, W. M. Itano, J. D. Jost, C. Langer, R. Ozeri, T. Schaetz, and D. J. Wineland, Science 308, 997 (2005); J. Chiaverini, D. Leibfried, T. Schaetz, M. D. Barnett, R. B. Blakestad, J. Britton, W. M. Itano, J. D. Jost, E. Knill, C. Langer, R. Ozeri, and D. J. Wineland, Science 308, 997 (2005); J. Chiaverini, D. Leibfried, T. Schaetz, M. D. Barnett, R. B. Blakestad, J. Britton, W. M. Itano, J. D. Jost, E. Knill, C. Langer, R. Ozeri, and D. J. Wineland, Nature 432, 602 (2004); M. A. Rowe, A. Ben-Kish, B. DeM arco, D. Leibfried, V. Meyer, J. Beall, J. Britton, J. Hughes, W. M. Itano, B. Jelenkovic,

C.Langer, T.Rosenband, and D.J.W ineland, Quantum Inf.Com put.2,257 (2002); W.K.Hensinger, S.Olm schenk, D.Stick, D. Hucul, M.Yeo, M.Acton, L.Deslauriers, and C.Monroe, Appl.Phys.Lett.88,034101 (2006).

- [B] C. Langer, R. Ozeri, J. D. Jost, J. Chiaverini, B. DeM arco, A. Ben-Kish, R. B. Blakestad, J. Britton, D. B. Hume, W. M. Itano, D. Leibfried, R. Reichle, T. Rosenband, T. Schaetz, P.O. Schmidt, and D. J.W ineland, Long-Lived Qubit M em ory U sing A tom ic Ions', Phys. Rev. Lett. 95, 060502 (2005).
- [9] J. J. Bollinger, D. J. Heinzen, W. M. Itano, S.L. G ilbert and D. J. W ineland, A 303M Hz frequency standard based on trapped Betions'. EEE Trans. Instrum. M eas. 40, 126 (1991).
- [10] H. Ha ner, T. Beier, S. D jekic, N. Hermanspahn, H.-J. K luge, W. Quint, S. Stahl, J. Verdu, T. Valenzuela, and G W erth, D ouble Penning trap technique for precise g factor determ inations in highly charged ions' Eur. Phys. J. D 22, 163182 (2003).
- [11] J.I.C irac and P.Zoller, A scalable quantum computer with ions in an array of m icrotraps', Nature, 404 579 (2000)
- [12] H.F. Powell, D.M. Segal, and R.C. Thompson, Axialization of Laser Cooled M agnesium Ions in a Penning Trap' Phys. Rev. Lett. 89 093003-1 (2002).